

1000MHz 22dB Gain With GaAs Power Double Amplifier Module

1. Product profile

1.1 General description

High dynamic range power doubler amplifier module operating at a supply voltage of 12VDC in an SOT115 package, using a cascaded power doubler MMIC with GaAs Technology from USA , adding ESD and surge protective devices.

CAUTION



This device is sensitive to Electro Static Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- n Excellent linearity
- n Low noise
- n Ultra-low CSO/CTB/XMOD
- n Rugged construction
- n High reliability

1.3 Applications

- n CATV systems operating in the 40MHz to 1000MHz frequency range.

1.4 Quick reference data

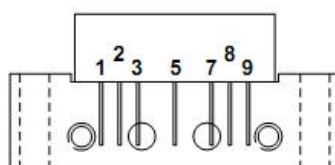
Bandwidth 40MHz to 1000MHz; $V_B = 12\text{ V}$; $T_{mb} = 30\text{ }^\circ\text{C}$; $Z_S = Z_L = 75\text{ }\Omega$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$f = 50\text{MHz}$	20.5	21.0	22.0	dB
		$f = 1000\text{MHz}$	21.5	-	-	dB
I_{tot}	total current	$V_B = 12\text{ V}$	610	645	680	mA

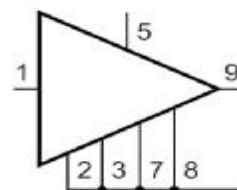
2. Pin information

Pin	Description
1	input
2	common
3	common
5	+ V_B
7	common
8	common
9	output

Simplified Outline



Graphic Symbol



3. Operating conditions

3.1 Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134) (TA = +25°C)

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V _B	-	12	V
Input Voltage ^[1]	V _i	-	65	dBmV
Operating Case Temperature	T _C	-20	+90	°C
Storage Temperature	T _{stg}	-40	+100	°C

[1] In case of single tone

3.2 Recommended operating conditions (Z_S = Z_L = 75 Ω)

Parameter	Symbol	Test Conditions	MIN	TYP	MAX	Unit
Supply Voltage	V _B		11	12	12	V
Operating Case Temperature	T _C		-20	+30	+80	°C

4. Electrical characteristics

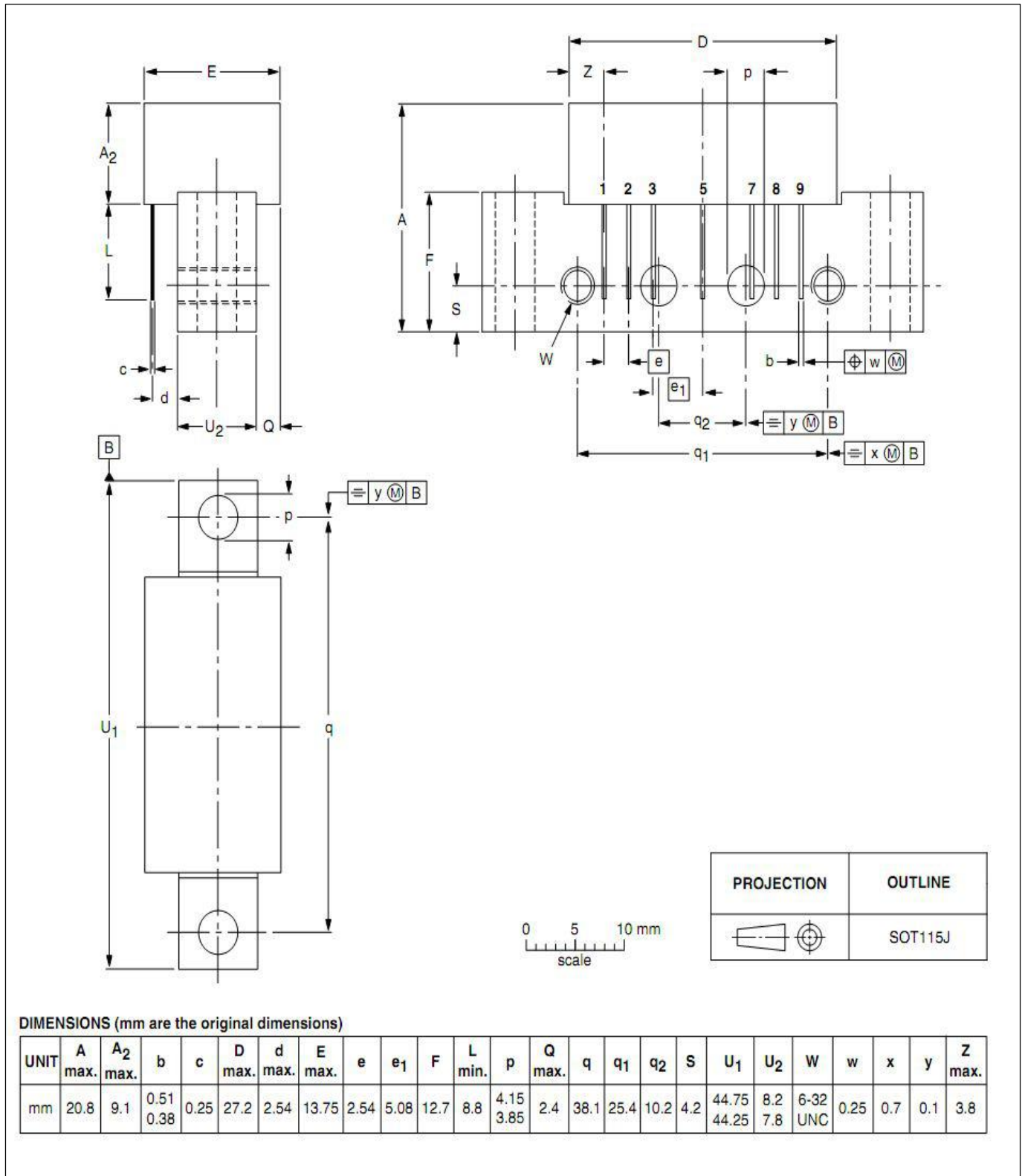
(T_C = 30±5°C, V_B = 12 V, Z_S = Z_L = 75 Ω)

Parameter	Symbol	Test Conditions	MIN	TYP	MAX	Unit
Power Gain	G _p	f = 50MHz	20.5	21.0	22.0	dB
Gain Slope	S _L	f = 50 to 1000MHz	1.0	1.5	2.5	dB
Gain Flatness	FL	f = 50 to 1000MHz	-	-	±0.5	dB
Noise Figure	NF	f = 1000MHz	-	5.0	5.5	dB
Operating Current	I _B	V _B =12VDC, RF OFF	610	645	680	mA
Composite Triple Beat	CTB	98 channels, V _o = 50dBmV at 855.25 MHz, flat output level across the band	-	-65	-	dB
Cross Modulation	XM		-	-62	-	dB
Composite 2nd Order Beat	CSO		-	-66	-	dB
Input Return Loss	S11	f = 40 to 550MHz	16	-	-	dB
		f = 550 to 1000MHz	16	-	-	dB
Output Return Loss	S22	f = 40 to 550MHz	16	-	-	dB
		f = 550 to 1000MHz	14	-	-	dB

5. Package outline

Rectangular single-ended package; aluminum flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads.

SOT115J



UNIT: mm